

Date:- 28<sup>th</sup> Feb, 2011

Data Sheet Issue:- 2

# **Rectifier Diode**

# Type W3697V#160 to W3697V#280

Old Type No.: SW02-20CXC16C

# **Absolute Maximum Ratings**

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
$V_{RRM}$	Repetitive peak reverse voltage, (note 1)	1600-2800	V
$V_{RSM}$	Non-repetitive peak reverse voltage, (note 1)	1700-2900	V

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
$I_{F(AV)M}$	Maximum average forward current, T <sub>sink</sub> =55℃, (note 2)	3697	А
$I_{F(AV)M}$	Maximum average forward current. T <sub>sink</sub> =100℃, (note 2)	2530	Α
I <sub>F(AV)M</sub>	Maximum average forward current. T <sub>sink</sub> =100℃, (note 3)	1520	Α
$I_{F(RMS)M}$	Nominal RMS forward current, T <sub>sink</sub> =25℃, (note 2)	6840	Α
I <sub>F(d.c.)</sub>	D.C. forward current, T <sub>sink</sub> =25℃, (note 4)	5840	А
I <sub>FSM</sub>	Peak non-repetitive surge t <sub>p</sub> =10ms, V <sub>m</sub> =0.6V <sub>RRM</sub> , (note 5)	40	kA
I <sub>FSM2</sub>	Peak non-repetitive surge t <sub>p</sub> =10ms, V <sub>m</sub> ≤10V, (note 5)	45	kA
l <sup>2</sup> t	$I^2$ t capacity for fusing $t_p$ =10ms, $V_{rm}$ =0.6 $V_{RRM}$ , (note 5)	8.0×10 <sup>6</sup>	A <sup>2</sup> s
l <sup>2</sup> t	I <sup>2</sup> t capacity for fusing t <sub>p</sub> =10ms, V <sub>rm</sub> ≤10V, (note 5)	10.1×10 <sup>6</sup>	A <sup>2</sup> s
T <sub>j op</sub>	Operating temperature range	-55 to +160	C
$T_{stg}$	Storage temperature range	-55 to +180	C

#### Notes:-

- 1) De-rating factor of 0.13% per  ${\mathfrak C}$  is applicable for T  $_{\rm j}$  below 25 ${\mathfrak C}$ .
- 2) Double side cooled, single phase; 50Hz, 180° half-sinewave.
- 3) Single side cooled, single phase; 50Hz, 180°half-sinewave.
- 4) Double side cooled.
- 5) Half-sinewave, 160°C T<sub>i</sub> initial.



# **Characteristics**

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
$V_{FM}$	Maximum peak forward voltage	-	-	1.54	I <sub>TM</sub> =6800A	V
$V_{FM}$	Maximum peak forward voltage	-	-	1.95	I <sub>TM</sub> =11100A	V
$V_{T0}$	Threshold voltage	-	-	0.86		V
r <sub>T</sub>	Slope resistance	-	-	0.10		mΩ
I <sub>RRM</sub>	Peak reverse current	-	-	60	Rated V <sub>RRM</sub>	mA
$I_{RRM}$	Peak reverse current	-	-	60	Rated V <sub>RRM</sub> , T <sub>j</sub> =25℃	mA
D	Thermal registance, junction to heataink	-	-	0.016	Double side cooled	K/W
$R_{thJK}$	Thermal resistance, junction to heatsink	-	-	0.032	Single side cooled	K/W
F	Mounting force	27	-	34		kN
۱۸/	Weight	-	800	-	Outline Options VF	g
$W_t$	Weight	-	1000	-	Outline Options VC, VT	g

#### Notes:-

- 1) Unless otherwise indicated T<sub>j</sub>=160°C.
- 2) For other clamp forces, please consult factory.

Notes on rupture rated packages.

This product is available with a non-rupture rated package.

For additional details on these products, please consult factory.



#### **Notes on Ratings and Characteristics**

# 1.0 Voltage Grade Table

Voltage Grade	$V_{DRM} V_{DSM} V_{RRM} V$	V <sub>RSM</sub> V	V <sub>D</sub> V <sub>R</sub> DC V
16	1600	1700	1050
18	1800	1900	1150
20	2000	2100	1250
22	2200	2300	1350
24	2400	2500	1450
26	2600	2700	1550
28	2800	2900	1600

# 2.0 Extension of Voltage Grades

This report is applicable to other voltage grades when supply has been agreed by Sales/Production.

#### 3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/℃ is applicable to this device for T<sub>i</sub> below 25℃.

#### 4.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

# 5.0 Computer Modelling Parameters

#### 5.1 Device Dissipation Calculations

$$I_{AV} = \frac{-V_0 + \sqrt{{V_0}^2 + 4 \cdot ff^2 \cdot r_s \cdot W_{AV}}}{2 \cdot ff^2 \cdot r_s} \quad \text{and:} \quad \begin{aligned} W_{AV} &= \frac{\Delta T}{R_{th}} \\ \Delta T &= T_{j \max} - T_{Hs} \end{aligned}$$

Where  $V_0=0.86V$ ,  $r_T=0.1m\Omega$ ,

 $R_{th}$  = Supplementary thermal impedance, see table below and

ff = Form factor, see table below.

Supplementary Thermal Impedance					
Conduction Angle 6 phase (60°) 3 phase (120°) ½ wave (180°) d.c.					
Square wave Double Side Cooled	0.0205	0.0190	0.0170	0.0160	
<u>'</u>					
Square wave Single Side Cooled	0.0400	0.0376	0.0340	0.0320	
Sine wave Double Side Cooled	0.0198	0.0177	0.0162		
Sine wave Single Side Cooled	0.0388	0.0355	0.0324		

Form Factors					
Conduction Angle 6 phase (60°) 3 phase (120°) ½ wave (180°) d.c.					
Square wave	2.449	1.732	1.414	1	
Sine wave	2.778	1.879	1.57		

### 5.2 Calculating V<sub>F</sub> using ABCD Coefficients

The on-state characteristic I<sub>F</sub> vs. V<sub>F</sub>, on page 6 is represented in two ways;

- (i) The well established  $V_0$  and  $r_T$  tangent used for rating purposes and
- (ii) A set of constants A, B, C, D, forming the coefficients of the representative equation for  $V_F$  in terms of  $I_F$  given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given below for hot characteristics. The resulting values for  $V_F$  agree with the true device characteristic over a current range, which is limited to that plotted.

	160℃ Coefficients
Α	0.2946829
В	0.100011
С	1.106436×10 <sup>-4</sup>
D	-4.781509×10 <sup>-3</sup>



# 5.3 D.C. Thermal Impedance Calculation

$$r_{t} = \sum_{p=1}^{p=n} r_{p} \cdot \left(1 - e^{\frac{-t}{\tau_{p}}}\right)$$

Where p = 1 to n, n is the number of terms in the series and:

t = Duration of heating pulse in seconds.

 $r_{\downarrow}$  = Thermal resistance at time t.

 $r_p$  = Amplitude of  $p_{th}$  term.  $r_p$  = Time Constant of  $r_{th}$  term.

The coefficients for this device are shown in the tables below:

D.C. Double Side Cooled						
Term	n 1 2 3 4					
$r_{\rho}$	6.850949×10 <sup>-3</sup>	6.006273×10 <sup>-3</sup>	1.872869×10 <sup>-3</sup>	1.385196×10 <sup>-3</sup>		
$ au_p$	1.219991	0.1764593	0.02313936	3.319288×10 <sup>-3</sup>		

	D.C. Single Side Cooled					
Term	1	2	3	4	5	
$r_{p}$	0.01803063	5.201877×10 <sup>-3</sup>	4.810704×10 <sup>-3</sup>	3.890524×10 <sup>-3</sup>	2.299757×10 <sup>-3</sup>	
$ au_{ m p}$	9.810556	4.974419	0.3591421	0.09925002	5.541104×10 <sup>-3</sup>	

# **Curves**

Figure 1 - Forward characteristics of Limit device

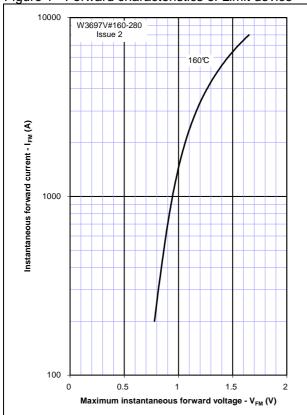


Figure 2 - Transient thermal impedance

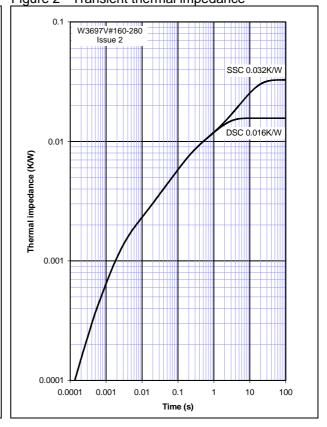


Figure 3 - Maximum surge Rating

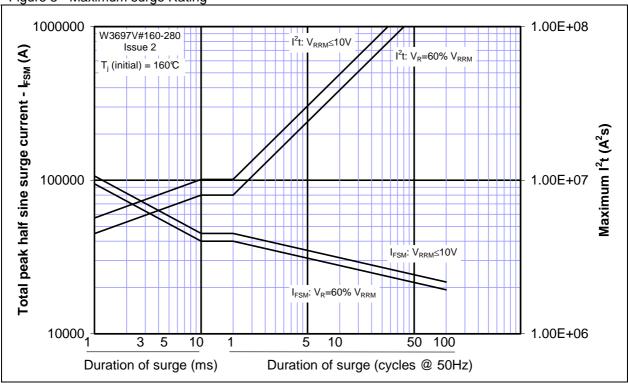


Figure 4 – Forward current vs. Power dissipation – Double Side Cooled

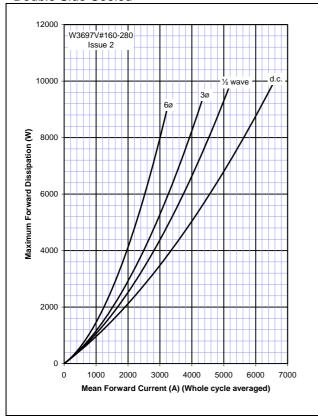


Figure 6 – Forward current vs. Power dissipation – Single Side Cooled

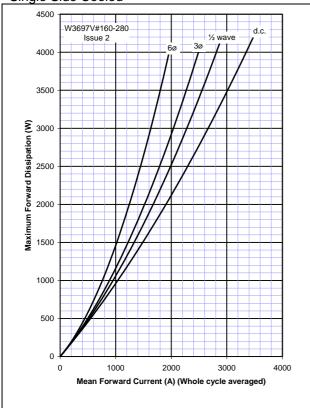


Figure 5 – Forward current vs. Heatsink temperature - Double Side Cooled

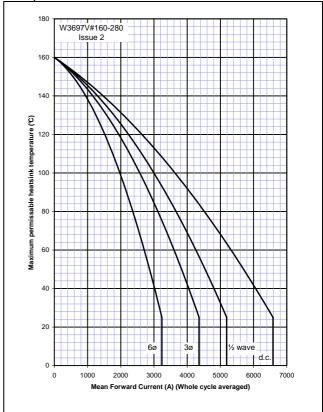
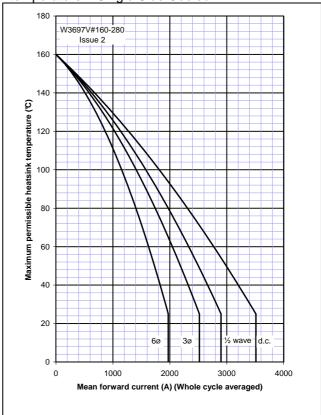
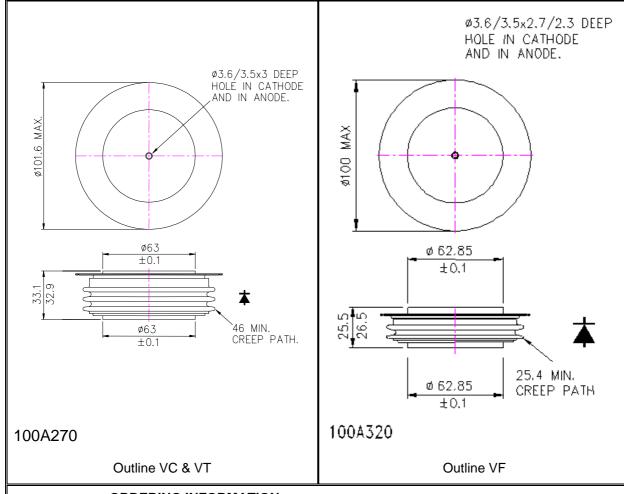


Figure 7 – Forward current vs. Heatsink temperature – Single Side Cooled



#### **Outline Drawing & Ordering Information**



ORD	ERING INFORMATION	(Please quote 10 digit cod	e as below)
W3697	V#	**	0
Fixed Type Code	Fixed outline code VC = 33mm Clamp height, VT = 33mm rupture rated capsule, VF = 26mm Clamp height	Voltage code V <sub>DRM</sub> /100 16-28	Fixed turn-off time code

Order code: W3697VC180 - 1800V V<sub>RRM</sub>, 33.1mm clamp height capsule.

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